





# **1 Product profile**

### 1.1 General description

Two planar PIN diodes in an SOT323 small SMD plastic package.

#### **1.2 Features and benefits**

- Two elements in common cathode configuration
- High voltage, current controlled
- RF resistor for RF switches
- Low diode capacitance
- Low diode forward resistance
- AEC-Q101 qualified

### 1.3 Applications

- RF attenuators and switches
- Bandswitch for TV tuners
- · Series diode for mobile communication transmit/receive switch



# 2 Pinning information

Table 1	I. Discrete pinning		
Pin	Description	Simplified outline	Graphic symbol
1	anode (a <sub>1</sub> )		
2	anode (a <sub>2</sub> )		
3	common cathode	1 2 sot323_so	
		Top view	

# **3** Ordering information

Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
BAP65-05W	-	plastic surface-mounted package; 3 leads	SOT323			

# 4 Marking

Table 3. Marking					
Type number	Marking code				
BAP65-05W	V6%				

# **5** Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>R</sub>	continuous reverse voltage		-	30	V
l <sub>F</sub>	continuous forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> ≤ 90 °C	-	240	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C

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Silicon PIN diode

# **6** Thermal characteristics

Table 5. Thermal characteristics							
Symbol	Parameter	Conditions	Тур	Unit			
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		250	K/W			

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# 7 Characteristics

#### Table 6. Characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
/ <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 mA		-	0.9	1.1	V
R	reverse leakage current	V <sub>R</sub> = 20 V		-	-	20	nA
C <sub>d</sub>	diode capacitance	f = 1 MHz (see <u>Figure 1</u> )					
		V <sub>R</sub> = 0 V		-	0.7	-	pF
		V <sub>R</sub> = 1 V		-	0.575	0.9	pF
		V <sub>R</sub> = 3 V		-	0.525	0.8	pF
		V <sub>R</sub> = 20 V		-	0.425	-	pF
D	diode forward resistance	f = 100 MHz (see <u>Figure 2</u> )					
		I <sub>F</sub> = 1 mA		-	1	-	Ω
		I <sub>F</sub> = 5 mA	[1]	-	0.65	0.95	Ω
		I <sub>F</sub> = 10 mA	[1]	-	0.56	0.9	Ω
		I <sub>F</sub> = 100 mA		-	0.35	-	Ω
ISL	isolation	V <sub>R</sub> = 0 V (see <u>Figure 4</u> )		1			
		f = 900 MHz		-	9.3	-	dB
		f = 1800 MHz		-	5.3	-	dB
		f = 2450 MHz		-	3.5	-	dB
L <sub>ins</sub>	insertion loss	See Figure 3.	See Figure 3.				
		I <sub>F</sub> = 1 mA					
		f = 900 MHz		-	0.11	-	dB
		f = 1800 MHz		-	0.17	-	dB
		f = 2450 MHz		-	0.24	-	dB
		I <sub>F</sub> = 5 mA		1	1		
		f = 900 MHz		-	0.08	-	dB
		f = 1800 MHz		-	0.14	-	dB
		f = 2450 MHz		-	0.21	-	dB
		I <sub>F</sub> = 10 mA					
		f = 900 MHz		-	0.08	-	dB
		f = 1800 MHz		-	0.14	-	dB
		f = 2450 MHz		-	0.21	-	dB
Lins	insertion loss	I <sub>F</sub> = 100 mA		1	I		
		f = 900 MHz		-	0.06	-	dB
		f = 1800 MHz		-	0.13	-	dB
		f = 2450 MHz		-	0.2	-	dB
				1		1	- I

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## Silicon PIN diode

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
τι	charge carrier life time	when switched from $I_F = 10 \text{ mA}$ to $I_R = 6 \text{ mA}$ ; $R_L = 100 \Omega$ ; measured at $I_R = 3 \text{ mA}$	-	0.17	-	μs
L <sub>S</sub>	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	1.4	-	nH

[1] Guaranteed on AQL basis; inspection level S4, AQL 1.0

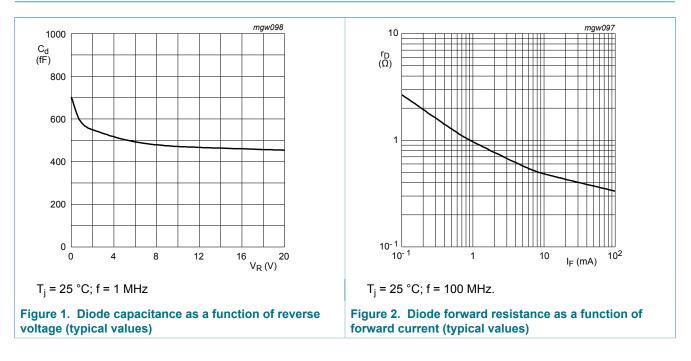
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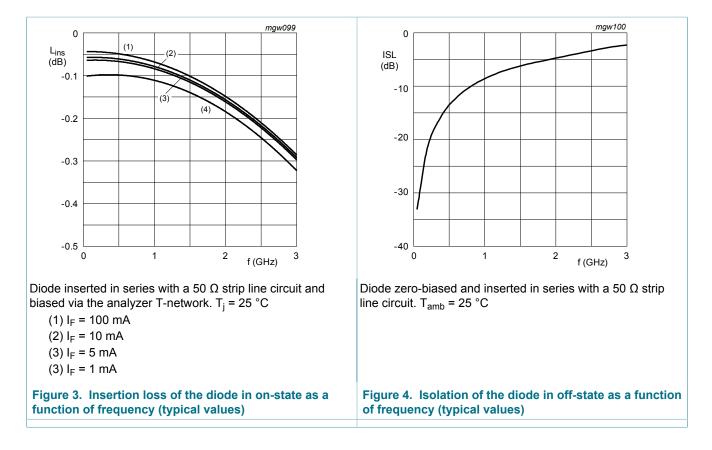
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# 8 Graphical data





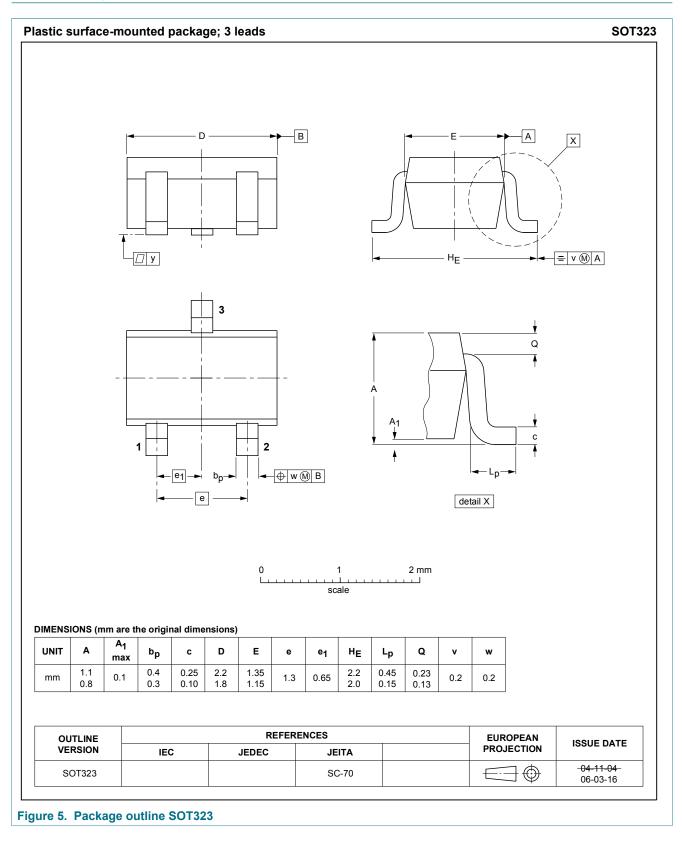
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# 9 Package outline



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# 10 Revision history

Table 7. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAP65-05W v.3.1	20190128	Product data sheet	-	BAP65-05W v.3	
Modifications:	Changed title to S	Silicon PIN diode			
BAP65-05W v.3	20181211	Product data sheet	-	BAP65-05W v.2	
Modifications:	<ul> <li><u>Section 1.2</u> "Features and benefits" has been updated.</li> <li>The "Legal information" pages have been updated.</li> </ul>				
BAP65-05W v.2	20100927	Product data sheet	-	BAP65-05W v.1	

# **11 Legal information**

### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

[2] [3] The term 'short data sheet' is explained in section "Definitions".

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